## **74AUP1T34**

# Low-power dual supply translating buffer

Rev. 6 — 28 January 2019

Product data sheet

## 1. General description

The 74AUP1T34 provides a single buffer with two separate supply voltages. Input A is designed to track V<sub>CC(A)</sub>. Output Y is designed to track V<sub>CC(Y)</sub>. Both, V<sub>CC(A)</sub> and V<sub>CC(Y)</sub> accepts any supply voltage from 1.1 V to 3.6 V. This feature allows universal low voltage interfacing between any of the 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V voltage nodes.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 1.1 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 1.1 V to 3.6 V. This device is fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 1.1 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Wide supply voltage range:
  - $V_{CC(A)}$ : 1.1 V to 3.6 V
  - V<sub>CC(Y)</sub>: 1.1 V to 3.6 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Each port operates over the full 1.1 V to 3.6 V power supply range
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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## 3. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AUP1T34GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1T34GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP1T34GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891				
74AUP1T34GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP1T34GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP1T34GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226				

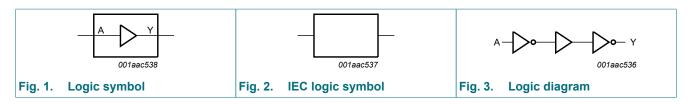
## 4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1T34GW	pQ
74AUP1T34GM	pQ
74AUP1T34GF	pQ
74AUP1T34GN	pQ
74AUP1T34GS	pQ
74AUP1T34GX	pQ

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram

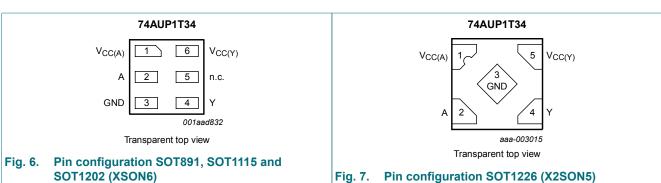


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## 6. Pinning information

### 6.1. Pinning





### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	TSSOP5 and X2SON5	XSON6		
V <sub>CC(A)</sub>	1	1	supply voltage port A	
Α	2	2	data input A	
GND	3	3	ground (0 V)	
Υ	4	4	data output Y	
n.c.	-	5	not connected	
V <sub>CC(Y)</sub>	5	6	supply voltage port Y	

## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output
A	Υ
L	L
Н	Н

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## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC(A)</sub>	supply voltage A		-0.5	+4.6	V
V <sub>CC(Y)</sub>	supply voltage Y		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC(Y)}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		1.1	3.6	V
$V_{CC(Y)}$	supply voltage Y		1.1	3.6	V
VI	input voltage		0	3.6	V
V <sub>O</sub>	output voltage		0	V <sub>CC(Y)</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	control and data inputs; V <sub>CC(A)</sub> = 1.1 V to 3.6 V	0	200	ns/V

### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
T <sub>amb</sub> = 2	T <sub>amb</sub> = 25 °C									
V <sub>IH</sub>	HIGH-level input	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	0.65V <sub>CC(A)</sub>	-	-	V				
	voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	1.6	-	-	V				
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	2.0	-	-	V				
$V_{IL}$	LOW-level input voltage	V <sub>CC(A)</sub> = 1.1 V to 1.95 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.35V <sub>CC(A)</sub>	V				
		$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.7	V				
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.9	V				

<sup>[2]</sup> For TSSOP5 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V <sub>CC(Y)</sub> - 0.1	-	-	V
V <sub>OL</sub>		$I_{O}$ = -1.1 mA; $V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$	0.75V <sub>CC(Y)</sub>	-	-	V
		$I_{O}$ = -1.7 mA; $V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O}$ = -1.9 mA; $V_{CC(A)} = V_{CC(Y)} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 V$	2.05	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 V$	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC(A)} = V_{CC(Y)} = 3.0 V$	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC(A)} = V_{CC(Y)} = 3.0 V$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_{l} = V_{lL}$				
	voltage	$I_O = 20 \mu A$ ; $V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		$I_{O} = 1.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$	-	-	0.3V <sub>CC(Y)</sub>	V
		$I_O = 1.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	-	-	0.31	V
		$I_O = 1.9 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 1.65 \text{ V}$	-	-	0.31	V
		$I_{O} = 2.3 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.31	V
		$I_O = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.44	V
		$I_O = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.31	V
		$I_O = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.44	V
I <sub>I</sub>	input leakage current	$V_{I} = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-			μΑ
I <sub>OFF</sub>	power-off leakage current	A input; $V_I = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V};$ $V_{CC(Y)} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.2	μΑ
		Y output; $V_O = 0 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(A)} = 0 \text{ V to } 3.6 \text{ V}$ ; $V_I = 0 \text{ V or } 3.6 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V}$	-	-	±0.2	μA
Δl <sub>OFF</sub>	additional power-off leakage	A input; $V_I = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V to } 0.2 \text{ V}; V_{CC(Y)} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.2	μΑ
	current	Y output; $V_O = 0 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(A)} = 0 \text{ V to } 3.6 \text{ V}$ ; $V_I = 0 \text{ V or } 3.6 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I <sub>CC</sub>	supply current	port A; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A		0.1 - 0.3V <sub>CC(Y)</sub> - 0.31 - 0.31 - 0.31 - 0.44 - 0.31 - 0.44 - ±0.1 - ±0.2 - ±0.2 - ±0.2 - ±0.2 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5 - 0.5		
		V <sub>CC(A)</sub> = V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.5	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V}$	-	-	- 0.31 - 0.44 - 0.31 - 0.44 - 0.44 - ±0.1 - ±0.2 - ±0.2 - ±0.2 - ±0.2 - 0.5 - 0.5 - 0.5	μA
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(Y)</sub> = 3.6 V	-	0.0		μΑ
		port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A				
		V <sub>CC(A)</sub> = V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.5	μΑ
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V}$	-	0.0	-	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(Y)} = 3.6 \text{ V}$	-	-	0.5	μA
		port A and port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_{I} = V_{CC(A)} - 0.6 \text{ V}$	-	-	40	μΑ
C <sub>I</sub>	input capacitance	A input; $V_{CC(A)} = V_{CC(Y)} = 0 \text{ V to } 3.6 \text{ V};$ $V_{I} = \text{GND or } V_{CC(A)}$	-	1.0	-	pF
Co	output capacitance	Y output; $V_O = GND$ ; $V_{CC(Y)} = 0 V$ ; $V_{CC(A)} = 0 V$ to 3.6 V	-	1.8	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC(A)</sub> = 1.1 V to 1.95 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	0.65V <sub>CC(A)</sub>	-	-	V
	voltage	V <sub>CC(A)</sub> = 2.3 V to 2.7 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	1.6	-	-	V
		V <sub>CC(A)</sub> = 3.0 V to 3.6 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC(A)</sub> = 1.1 V to 1.95 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.35V <sub>CC(A)</sub>	V
	voltage	V <sub>CC(A)</sub> = 2.3 V to 2.7 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.7	V
		V <sub>CC(A)</sub> = 3.0 V to 3.6 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V <sub>CC(Y)</sub> - 0.1	-	-	V
		$I_{O}$ = -1.1 mA; $V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$	0.7V <sub>CC(Y)</sub>	-	-	V
		$I_{O}$ = -1.7 mA; $V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O}$ = -1.9 mA; $V_{CC(A)} = V_{CC(Y)} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	1.85	-	-	V
		$I_O = -2.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_1 = V_{1L}$				
		$I_O = 20 \mu A$ ; $V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		$I_O = 1.1 \text{ mA; } V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$	-	-	0.3V <sub>CC(Y)</sub>	V
		$I_O = 1.7 \text{ mA}$ ; $V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	-	-	0.37	V
		$I_{O} = 1.9 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 1.65 \text{ V}$	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.33	V
		$I_O = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.45	V
		$I_O = 2.7 \text{ mA}$ ; $V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.33	V
		$I_{O} = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.45	V
l <sub>l</sub>	input leakage current	$V_I = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	eakage A input; $V_I = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V}; V_{CC(Y)} = 0 \text{ V to } 3.6 \text{ V}$		-	±0.5	μΑ
		Y output; $V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V to } 3.6 \text{ V}; V_I = 0 \text{ V or } 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V}$	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage	A input; $V_I = 0 \text{ V to } 3.6 \text{ V}$ ; $V_{CC(A)} = 0 \text{ V to } 0.2 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.6	μΑ
	current	Y output; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 0 V to 3.6 V; V <sub>I</sub> = 0 V or 3.6 V; V <sub>CC(Y)</sub> = 0 V to 0.2 V	-	-	±0.6	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	port A; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A				
		V <sub>CC(A)</sub> = V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.9	μΑ
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(Y)</sub> = 0 V	-	-	0.9	μΑ
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(Y)</sub> = 3.6 V	-	0.0	-	μΑ
		port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A				
		V <sub>CC(A)</sub> = V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.9	μΑ
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(Y)</sub> = 0 V	-	0.0	-	μΑ
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(Y)</sub> = 3.6 V	-	-	0.9	μΑ
		port A and port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_{I} = V_{CC(A)} - 0.6 \text{ V}$	-	-	50	μA
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	0.7V <sub>CC(A)</sub>	-	-	V
	voltage	V <sub>CC(A)</sub> = 2.3 V to 2.7 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	1.6	-	-	V
		V <sub>CC(A)</sub> = 3.0 V to 3.6 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.3V <sub>CC(A)</sub>	V
		V <sub>CC(A)</sub> = 2.3 V to 2.7 V; V <sub>CC(Y)</sub> = 1.1 V to 3.6 V	-	-	0.7	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.9	V
$V_{OH}$	HIGH-level output	$V_I = V_{IH}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V <sub>CC(Y)</sub> - 0.11	-	-	V
		$I_{O}$ = -1.1 mA; $V_{CC(A)} = V_{CC(Y)} = 1.1 V$	0.6V <sub>CC(Y)</sub>	-	-	V
		$I_{O}$ = -1.7 mA; $V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O}$ = -1.9 mA; $V_{CC(A)} = V_{CC(Y)} = 1.65 \text{ V}$	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 V$	1.77	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC(A)} = V_{CC(Y)} = 3.0 V$	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	2.30	-	-	V
$V_{OL}$	LOW-level output	$V_I = V_{IL}$				
	voltage	$I_O = 20 \mu A; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC(A)</sub> = V <sub>CC(Y)</sub> = 1.1 V	-	-	0.33V <sub>CC(Y)</sub>	V
		$I_{O}$ = 1.7 mA; $V_{CC(A)} = V_{CC(Y)} = 1.4 \text{ V}$	-	-	0.41	V
		$I_{O}$ = 1.9 mA; $V_{CC(A)} = V_{CC(Y)} = 1.65 V$	-	-	0.39	V
		$I_{O}$ = 2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.36	V
		$I_O = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.50	V

### Low-power dual supply translating buffer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>I</sub>	input leakage current	$V_I = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	A input; $V_I$ = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V; $V_{CC(Y)}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
		Y output; $V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V to } 3.6 \text{ V}; V_I = 0 \text{ V or } 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V}$	-	-	±0.75	μA
$\Delta I_{OFF}$	additional power-off leakage	A input; $V_I$ = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V to 0.2 V; $V_{CC(Y)}$ = 0 V to 3.6 V	-	-	±0.75	μA
	current	Y output; $V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC(A)} = 0 \text{ V to } 3.6 \text{ V}; V_I = 0 \text{ V or } 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I <sub>CC</sub>	supply current	port A; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(Y)</sub> = 0 V	-	-	1.4	μΑ
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(Y)</sub> = 3.6 V	-	0.0	-	μΑ
		port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(Y)</sub> = 0 V	-	0.0	-	μΑ
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(Y)</sub> = 3.6 V	-	-	1.4	μΑ
		port A and port Y; $V_I$ = GND or $V_{CC(A)}$ ; $I_O$ = 0 A; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	1.4	μA
ΔI <sub>CC</sub>	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$ ; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_I = V_{CC(A)} - 0.6 \text{ V}$	-	-	75	μA

## 11. Dynamic characteristics

### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	25 °C			-40	Unit		
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 5 p	F; V <sub>CC(A)</sub> = 1.1 \	/ to 1.3 V							'
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.6	9.8	25.4	2.3	25.9	25.9	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.4	7.1	15.3	2.2	16.3	16.7	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.1	6.0	12.7	1.9	13.8	14.3	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.0	5.1	9.8	2.0	10.5	10.9	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.1	4.7	8.8	1.9	9.1	9.3	ns
C <sub>L</sub> = 5 p	F; V <sub>CC(A)</sub> = 1.4 \	/ to 1.6 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.3	9.1	23.9	2.0	24.5	24.5	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.1	6.4	13.6	1.9	14.7	15.2	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	1.8	5.3	10.9	1.6	12.1	12.6	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.7	4.3	7.8	1.6	8.7	9.2	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	1.8	3.9	6.6	1.6	7.1	7.5	ns

## Low-power dual supply translating buffer

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 5 p	F; V <sub>CC(A)</sub> = 1.65	5 V to 1.95 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.2	8.8	23.2	1.9	23.9	24.0	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.0	6.0	13.0	1.8	14.1	14.6	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	1.8	4.9	10.3	1.5	11.4	12.0	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.6	3.9	7.2	1.5	8.0	8.5	ns
		$V_{CC(Y)} = 3.0 \text{ V to } 3.6 \text{ V}$	1.7	3.5	5.9	1.5	6.4	6.8	ns
C <sub>L</sub> = 5 p	F; $V_{CC(A)} = 2.3$	V to 2.7 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.2	8.4	22.8	1.9	23.4	23.4	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	1.9	5.7	12.3	1.8	13.4	14.0	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	1.7	4.6	9.6	1.5	10.7	11.2	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.5	3.5	6.3	1.5	7.2	7.7	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	1.6	3.1	5.1	1.4	5.6	6.0	ns
C <sub>L</sub> = 5 p	$F; V_{CC(A)} = 3.0$	V to 3.6 V				l	1	1	
t <sub>pd</sub> propagation		A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.2	8.1	22.5	1.9	22.9	22.9	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	1.9	5.4	12.0	1.8	12.9	13.4	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	1.7	4.3	9.2	1.5	10.2	10.7	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.5	3.3	6.0	1.5	6.7	7.2	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	1.6	2.9	4.8	1.4	5.2	5.5	ns
C <sub>L</sub> = 10	pF; V <sub>CC(A)</sub> = 1.1	I V to 1.3 V					1	1	'
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.6	10.7	27.1	2.5	27.6	27.6	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.6	7.7	16.7	2.3	17.5	17.6	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.7	6.6	13.4	2.4	14.2	14.7	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.2	5.6	10.3	2.2	11.0	11.4	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.5	5.3	9.5	2.2	9.7	10.0	ns
C <sub>L</sub> = 10	pF; V <sub>CC(A)</sub> = 1.4	↓ V to 1.6 V					1	1	'
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.4	10.0	25.6	2.2	26.1	26.1	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.4	7.0	15.0	2.0	15.8	16.4	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.4	5.9	11.6	2.1	12.5	13.1	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.0	4.8	8.4	1.9	9.2	9.7	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.2	4.4	7.4	1.9	7.7	8.1	ns
C <sub>L</sub> = 10	pF; V <sub>CC(A)</sub> = 1.6	65 V to 1.95 V		1					
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.3	9.7	24.8	2.1	25.5	25.7	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.3	6.6	14.3	2.0	15.3	15.8	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.3	5.5	11.0	2.0	11.9	12.5	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.9	4.4	7.7	1.8	8.6	9.0	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.1	4.0	6.6	1.8	7.1	7.4	ns

## Low-power dual supply translating buffer

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 10	pF; V <sub>CC(A)</sub> = 2.3	3 V to 2.7 V					<u>'</u>	<u> </u>	
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	$V_{CC(Y)} = 1.1 \text{ V to } 1.3 \text{ V}$	2.3	9.3	24.4	2.1	25.1	25.1	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.2	6.3	13.6	1.9	14.6	15.1	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.2	5.1	10.3	2.0	11.2	11.7	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.8	4.1	6.9	1.8	7.7	8.2	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.0	3.6	5.8	1.7	6.3	6.6	ns
C <sub>L</sub> = 10	pF; $V_{CC(A)} = 3.0$	V to 3.6 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.3	9.0	24.2	2.1	24.6	24.6	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.2	6.0	13.3	1.9	14.1	14.6	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.2	4.9	9.9	2.0	10.6	11.2	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	1.8	3.9	6.5	1.8	7.3	7.7	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.0	3.5	5.4	1.7	5.8	6.2	ns
C <sub>L</sub> = 15	pF; V <sub>CC(A)</sub> = 1.1	V to 1.3 V					1	'	
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.0	11.5	28.6	2.8	29.2	29.2	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.1	8.3	17.3	2.7	18.6	19.1	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.8	7.1	14.1	2.7	15.2	15.8	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.6	6.1	11.1	2.7	11.6	12.1	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.9	5.7	9.9	2.6	10.3	10.6	ns
C <sub>L</sub> = 15	pF; V <sub>CC(A)</sub> = 1.4	V to 1.6 V					1	1	
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.8	10.8	27.1	2.6	27.7	27.7	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.8	7.6	15.7	2.4	17.0	17.6	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.5	6.3	12.3	2.4	13.5	14.1	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.3	5.3	9.2	2.4	9.9	10.3	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.6	4.9	7.8	2.3	8.3	8.7	ns
C <sub>L</sub> = 15	pF; V <sub>CC(A)</sub> = 1.6	65 V to 1.95 V						'	
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.7	10.5	26.4	2.5	27.1	27.3	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.7	7.2	15.0	2.3	16.4	17.0	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.4	6.0	11.7	2.3	12.8	13.5	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.2	4.9	8.5	2.2	9.2	9.7	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.5	4.5	7.1	2.2	7.7	8.0	ns
C <sub>L</sub> = 15	pF; V <sub>CC(A)</sub> = 2.3	3 V to 2.7 V		1					
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.6	10.1	26.0	2.4	26.7	26.7	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.7	6.9	14.3	2.3	15.7	16.3	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.4	5.6	10.9	2.2	12.1	12.7	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.1	4.5	7.6	2.2	8.4	8.9	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.4	4.1	6.2	2.1	6.8	7.2	ns

## Low-power dual supply translating buffer

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ [1] Max		Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 15	pF; $V_{CC(A)} = 3.0$	V to 3.6 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	2.6	9.8	25.7	2.4	26.2	26.2	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	2.7	6.6	14.0	2.3	15.2	15.7	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	2.4	5.4	10.5	2.2	11.6	12.1	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.1	4.3	7.3	2.2	7.9	8.4	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	2.4	3.9	5.9	2.1	6.4	6.8	ns
C <sub>L</sub> = 30	pF; V <sub>CC(A)</sub> = 1.1	V to 1.3 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.7	13.7	32.9	3.5	33.5	33.5	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.6	9.8	19.5	3.6	20.9	21.4	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	3.7	8.4	15.9	3.5	17.0	17.7	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	3.0	7.2	12.2	3.4	12.7	13.2	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	3.8	6.8	10.9	3.4	12.2	12.5	ns
C <sub>L</sub> = 30	pF; V <sub>CC(A)</sub> = 1.4	V to 1.6 V				l	'	1	
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.5	13.1	31.5	3.2	32.0	32.0	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.3	9.1	17.8	3.3	19.2	19.9	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	3.4	7.6	14.2	3.2	15.4	16.0	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.8	6.4	10.3	3.1	11.0	11.5	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	3.5	5.9	8.9	3.1	10.1	10.5	ns
C <sub>L</sub> = 30	pF; V <sub>CC(A)</sub> = 1.6	55 V to 1.95 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.4	12.7	30.7	3.1	31.5	31.5	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.2	8.8	17.2	3.2	18.7	19.3	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	3.3	7.3	13.5	3.1	14.7	15.4	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.7	6.0	9.6	3.0	10.4	10.9	ns
		$V_{CC(Y)} = 3.0 \text{ V to } 3.6 \text{ V}$	3.4	5.6	8.2	2.9	9.4	9.8	ns
C <sub>L</sub> = 30	pF; $V_{CC(A)} = 2.3$	S V to 2.7 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.3	12.4	30.3	3.1	31.0	31.0	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.2	8.4	16.5	3.1	18.0	18.7	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	3.2	6.9	12.8	3.0	14.0	14.6	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.6	5.6	8.8	2.9	9.6	10.1	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	3.3	5.2	7.3	2.9	8.5	9.0	ns
C <sub>L</sub> = 30	pF; V <sub>CC(A)</sub> = 3.0	V to 3.6 V							
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]							
	delay	V <sub>CC(Y)</sub> = 1.1 V to 1.3 V	3.3	12.0	30.0	3.1	30.5	30.5	ns
		V <sub>CC(Y)</sub> = 1.4 V to 1.6 V	3.2	8.1	16.2	3.1	17.5	18.1	ns
		V <sub>CC(Y)</sub> = 1.65 V to 1.95 V	3.2	6.7	12.4	3.0	13.4	14.1	ns
		V <sub>CC(Y)</sub> = 2.3 V to 2.7 V	2.6	5.5	8.5	2.9	9.1	9.6	ns
		V <sub>CC(Y)</sub> = 3.0 V to 3.6 V	3.2	5.0	7.0	2.9	8.1	8.5	ns

#### Low-power dual supply translating buffer

Symbol	Parameter	Conditions		25 °C			-40 °C to +125 °C			Unit
			М	in	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 5 p	F, 10 pF, 15 pF	and 30 pF	'							
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz};$ [3 $V_I = \text{GND to } V_{CC(A)}$	3][4]							
		$V_{CC(A)} = V_{CC(Y)} = 1.2 \text{ V}$		•	3.8	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 1.5 \text{ V}$		•	3.8	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 1.8 \text{ V}$		-	4.1	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 2.5 \text{ V}$		-	4.2	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 3.3 \text{ V}$		-	4.6	-	-	-	-	pF

- All typical values are measured at nominal  $V_{\text{CC}}$ .
- $t_{\text{pd}}$  is the same as  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$ .
- [3] All specified values are the average typical values over all stated loads.
- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

 $f_o$  = output frequency in MHz;

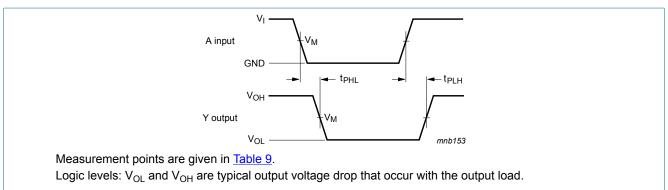
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

#### 11.1. Waveforms and test circuit

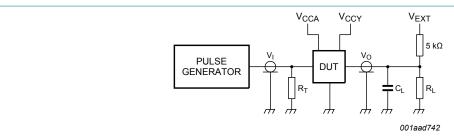


The data input (A) to output (Y) propagation delays

**Table 9. Measurement points** 

Supply voltage	Output	Input				
$V_{CC(A)}/V_{CC(Y)}$	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$		
1.1 V to 3.6 V	0.5 × V <sub>CC(Y)</sub>	0.5 × V <sub>CC(A)</sub>	V <sub>CC(A)</sub>	≤ 3.0 ns		

## Low-power dual supply translating buffer



Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig. 9. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>	
$V_{CC(A)}/V_{CC(Y)}$	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>
1.1 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5$ k $\Omega$ or $1$ M $\Omega$	open

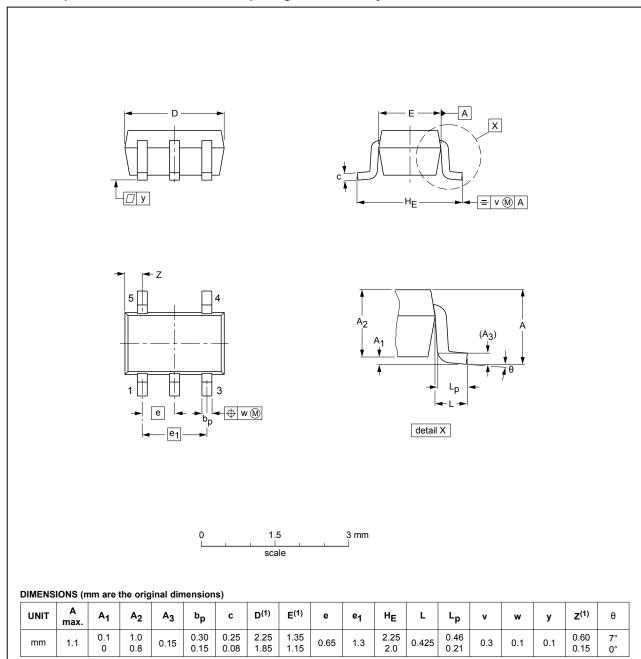
[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

## Low-power dual supply translating buffer

## 12. Package outline

### TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT353-1		MO-203	SC-88A			<del>-00-09-01</del> 03-02-19	

Fig. 10. Package outline SOT353-1 (TSSOP5)

### Low-power dual supply translating buffer

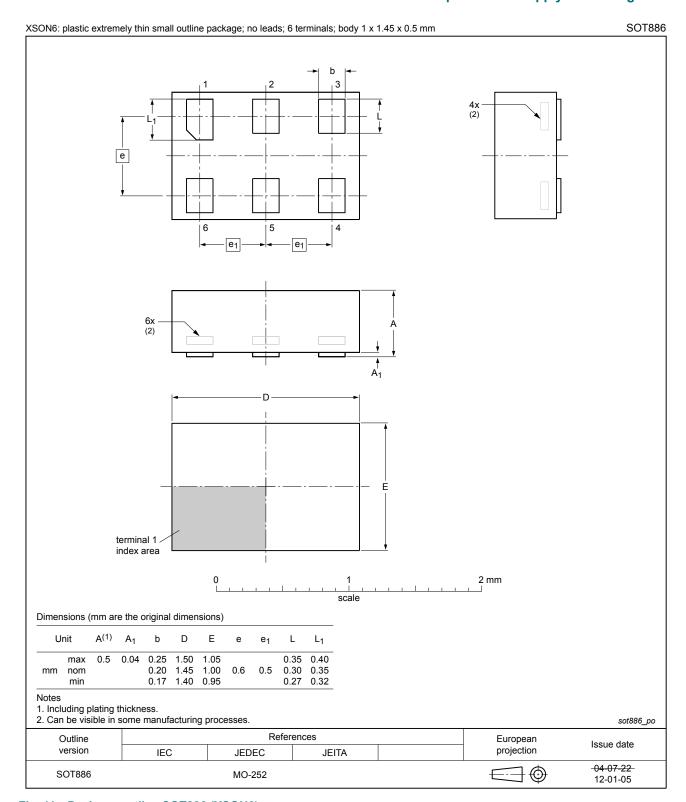


Fig. 11. Package outline SOT886 (XSON6)

## Low-power dual supply translating buffer

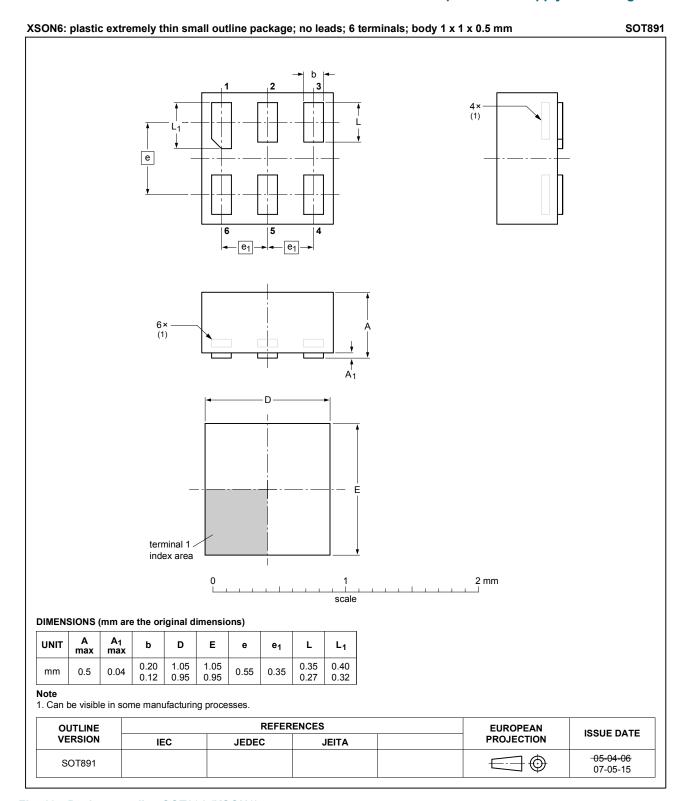


Fig. 12. Package outline SOT891 (XSON6)

## Low-power dual supply translating buffer

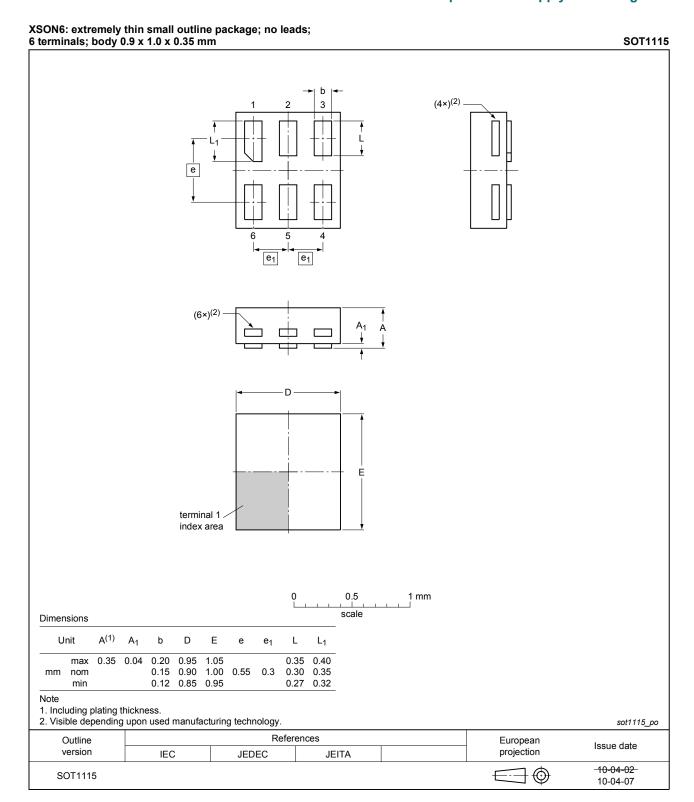


Fig. 13. Package outline SOT1115 (XSON6)

## Low-power dual supply translating buffer

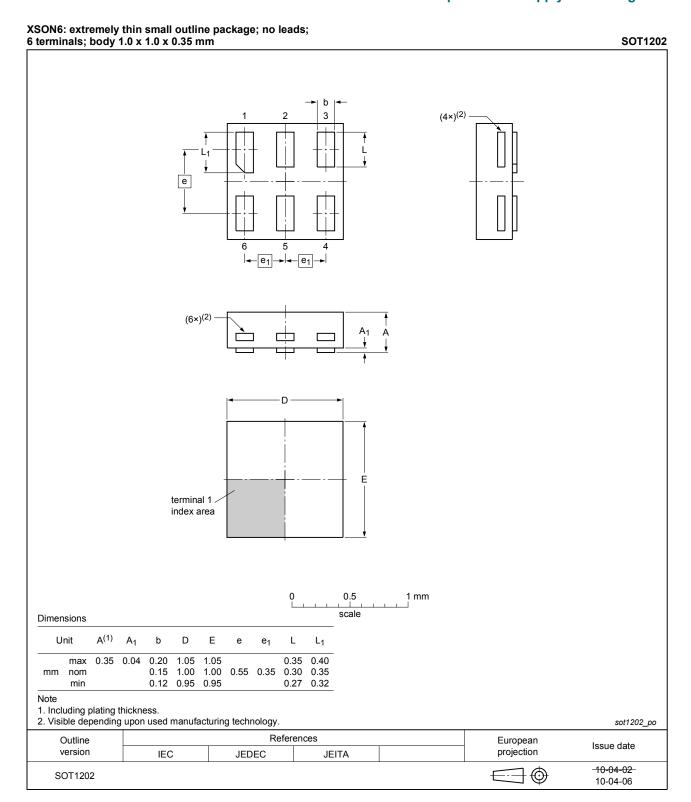


Fig. 14. Package outline SOT1202 (XSON6)

#### Low-power dual supply translating buffer

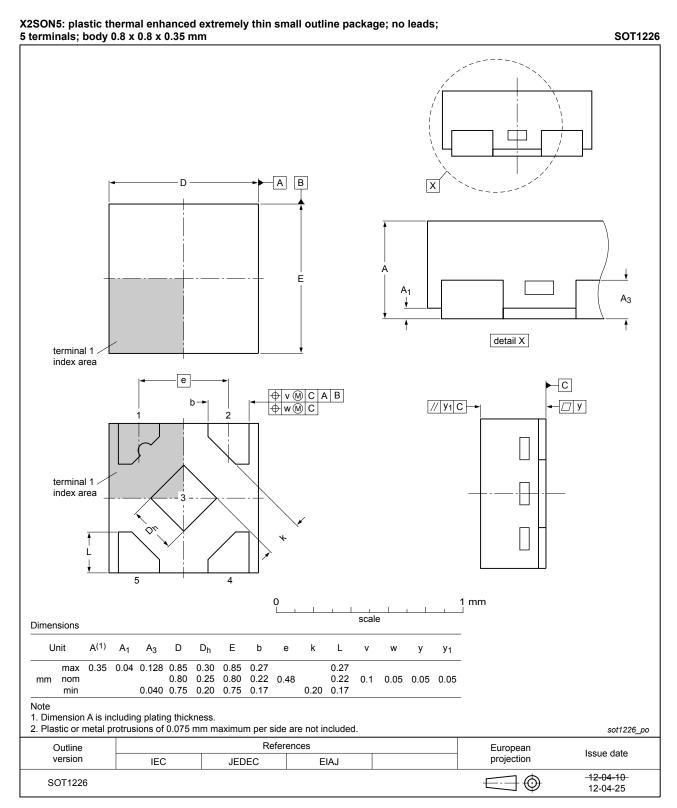


Fig. 15. Package outline SOT1226 (X2SON5)

### Low-power dual supply translating buffer

## 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

## 14. Revision history

#### **Table 12. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1T34 v.6	20190128	Product data sheet	-	74AUP1T34 v.5			
Modifications:	The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.						
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the no	ew company nam	e where appropriate.			
74AUP1T34 v.5	20130904	Product data sheet	-	74AUP1T34 v.4			
Modifications:	Added type i	number 74AUP1T34GX (SC	OT1226)				
74AUP1T34 v.4	20120316	Product data sheet	-	74AUP1T34 v.3			
Modifications:	Package out	line drawing of SOT886 (Fi	g. 11) modified.				
74AUP1T34 v.3	20111128	Product data sheet	-	74AUP1T34 v.2			
Modifications:	<ul> <li>Legal pages</li> </ul>	updated.					
74AUP1T34 v.2	20100819	Product data sheet	-	74AUP1T34 v.1			
74AUP1T34 v.1	20061204	Product data sheet	-	-			

#### Low-power dual supply translating buffer

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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